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TOSHIBA Photocoupler Photorelay

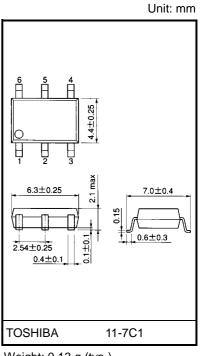
TLP3120

High-Speed Memory Tester High-Speed Logic Tester High-Frequency Measurement Equipment

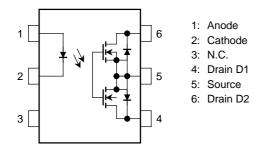
The Toshiba TLP3120 consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a SOP, which is suitable for surface mount assembly.

- 6-pin SOP (2.54SOP6): 2.1 mm high, 2.54 mm pitch
- Normally opened (form A) device
- Peak OFF-state voltage: 80 V (min)
- Trigger LED current: 5 mA (max)
- ON-state current: 1.25 A (max)
- ON-state resistance: 0.15Ω (max)
- Capacitance: 1000 pF (max)
- Isolation voltage: 1500 V_{rms} (min)

Pin Configuration (top view)



Weight: 0.13 g (typ.)



Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
	Forward current	١ _F	50	mA	
ed	Forward current derating (Ta \ge 25°C)	∆l _F /°C	-0.5	mA/°C	
Ľ	Reverse voltage	V _R	5	V	
	Junction temperature	Tj	125	°C	
	OFF-state output terminal voltage	VOFF	80	V	
Detector	ON-state current	I _{ON}	1.25	A	
Dete	ON-state current derating (Ta \ge 25°C)	∆l _{ON} /°C	-12.5	mA/°C	
	Junction temperature	Tj	125	°C	
Storage temperature range		T _{stg}	-40~125	°C	
Operating temperature range		T _{opr}	-20~85	°C	
Lead soldering temperature (10 s)		T _{sol}	260	°C	
Isolat	ion voltage (AC, 1 min, R.H. \leq 60%) (Note 1)	BVs	1500	Vrms	

Note 1: Device is considered as a two-terminal device. LED side pins are shorted together and detector side pins are shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V _{DD}			64	V
Forward current	١ _F	5	_	30	mA
ON-state current	I _{ON}	_	_	1.25	А
Operating temperature	T _{opr}	25		60	°C

Individual Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward current	VF	I _F = 10 mA	1.0	1.15	1.3	V
Led	Reverse current	I _R	$V_R = 5 V$		_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz		15	_	pF
Detector	OFF-state current	I _{OFF}	V _{OFF} = 20 V, Ta = 50°C		1200	1500	pА
Dete	Capacitance	C _{OFF}	V = 0, f = 100 MHz		460	1000	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}	I _{ON} = 1.25 A	_	2	5	mA
Return LED current	I _{FC}	I _{OFF} = 10 μA	0.2			mA
ON-state resistance	R _{ON}	I _{ON} = 1.25 A, I _F = 5 mA		0.11	0.15	Ω

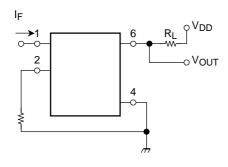
Isolation Characteristics (Ta = 25°C)

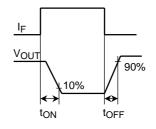
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	$V_{S} = 0 V$, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	$V_S = 500 \text{ V}, \text{ R.H.} \leq 60\%$	5×10^{10}	10 ¹⁴	_	Ω
		AC, 1 min	1500	_	_	Vrms
Isolation voltage	BVS	AC, 1 s (in oil)	_	3000	_	VIIIS
		DC, 1 min (in oil)	—	3000		Vdc

Switching Characteristics (Ta = 25°C)

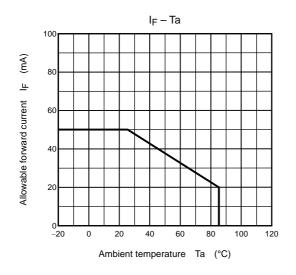
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-ON time	ton	$R_L = 200 \ \Omega$	_	2.0	3.0	ms
Turn-OFF time	tOFF	$V_{DD} = 20 \text{ V}, \text{ I}_{\text{F}} = 5 \text{ mA} \qquad (\text{Note 2})$		0.7	1.0	1115

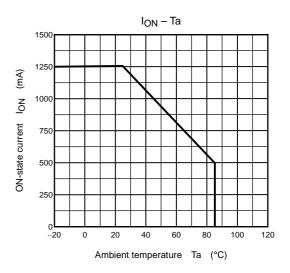
Note 2: Switching time test circuit

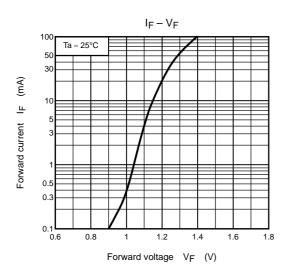


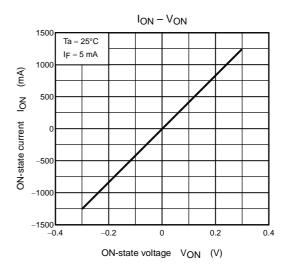


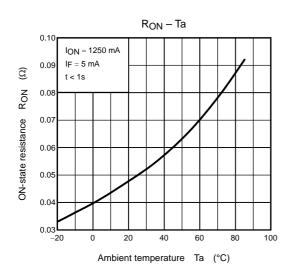
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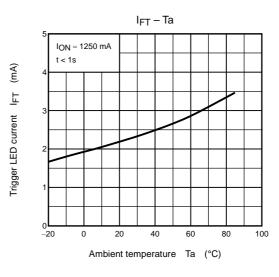




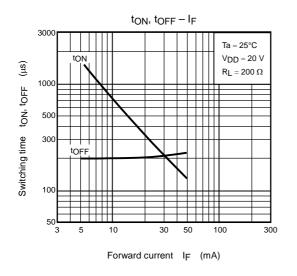


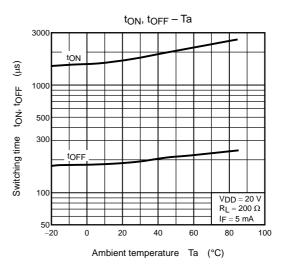


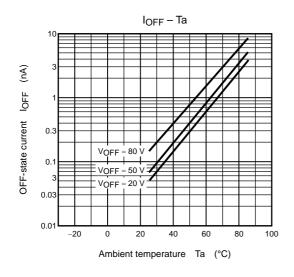




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